AUTOMOTIVE

ROHS

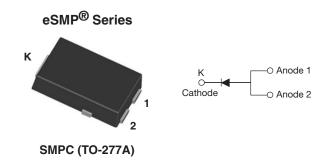
**HALOGEN** 

FREE



## Vishay Semiconductors

# Ultrafast Rectifier, 8 A FRED Pt®



#### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	8 A			
V <sub>R</sub>	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.01 V			
t <sub>rr (typ.)</sub>	42 ns			
T <sub>J</sub> max.	175 °C			
Package	SMPC (TO-277A)			
Circuit configuration	Single			

#### **FEATURES**

- Ultrafast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC, CRM snubber operation
- Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### **DESCRIPTION / APPLICATIONS**

State of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

### **MECHANICAL DATA**

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V	
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>Sp</sub> = 137 °C	8	۸	
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	120	А	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A	-	1.16	1.36	V
		I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.01	1.24	
Reverse leakage current	I <sub>R</sub>	$V_R = V_R$ rated	-	-	5	
		$T_J = 150 ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	25	150	μA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	8	-	pF



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time t <sub>rr</sub>		$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		i	42	-	ns
	t <sub>rr</sub>	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		1	-	60	
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 500 A/μs V <sub>R</sub> = 400 V	-	63	-	A nC
		T <sub>J</sub> = 125 °C		-	88	-	
Peak recovery current I <sub>R</sub>	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	12	-	
		T <sub>J</sub> = 125 °C		-	17	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	460	-	
		T <sub>J</sub> = 125 °C		ı	930	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction to mount	R <sub>thJM</sub>		-	2.4	3.5	°C/W
Approximate weight				0.1		g
Marking device		Case style SMPC (TO-277A)	QEU6			

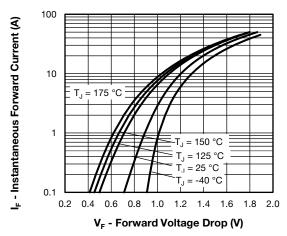


Fig. 1 - Typical Forward Voltage Drop Characteristics

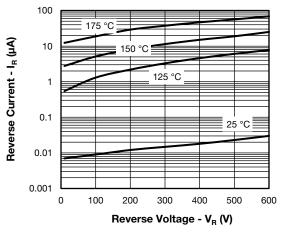


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

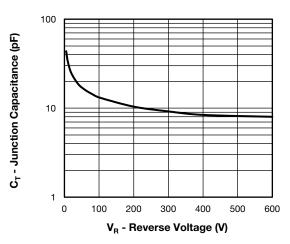


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

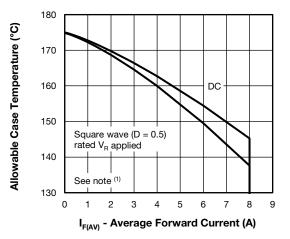


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current



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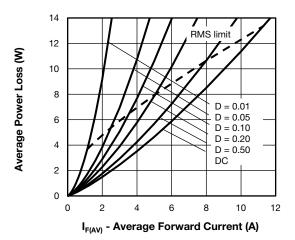


Fig. 5 - Forward Power Loss Characteristics

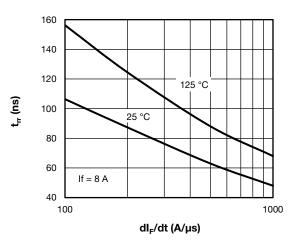


Fig. 6 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

## Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 5); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = rated V<sub>R</sub>

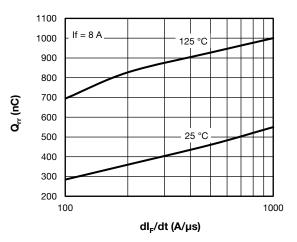


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

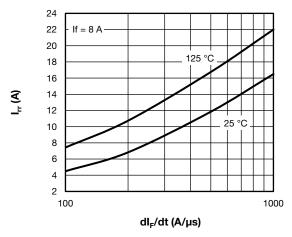
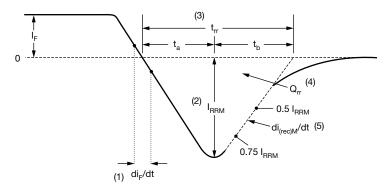


Fig. 8 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

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- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm l_{r}$  to point where a line passing through 0.75  $\rm l_{RRM}$  and 0.50  $\rm l_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$

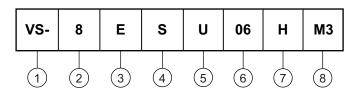
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions

### **ORDERING INFORMATION TABLE**

### **Device code**



- 1 Vishay Semiconductors product
- Current rating (8 = 8 A)
- 3 Circuit configuration:

E = single diode

- 4 S = SMPC package
- 5 Process type,

U = ultra fast recovery

- 6 Voltage code (06 = 600 V)
- 7 H = AEC-Q101 qualified
- M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-8ESU06HM3/H	1500	1500	7" diameter plastic tape and reel			
VS-8ESU06HM3/I	6500	6500	13" diameter plastic tape and reel			

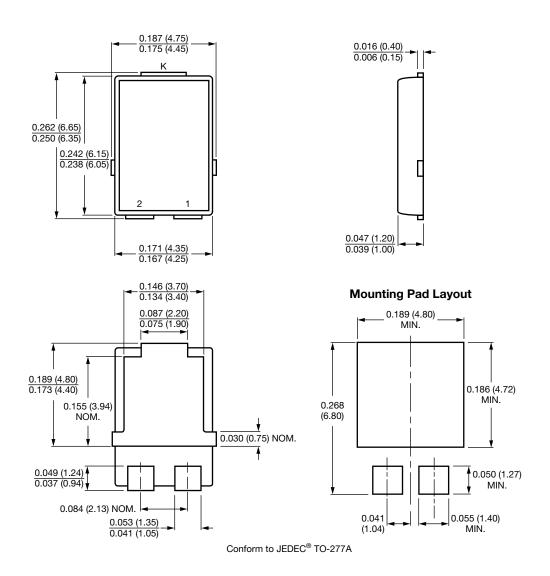
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95570				
Part marking information	www.vishay.com/doc?95565				
Packaging information	www.vishay.com/doc?88869				



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# **SMPC (TO-277A)**

## **DIMENSIONS** in inches (millimeters)





## **Legal Disclaimer Notice**

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